

Zener Diode DZ3X062D0L

## DZ3X062D0L Silicon epitaxial planar type

For surge absorption circuit

- Features
- · Excellent rising characteristics of zener current Iz
- Low zener operating resistance Rz
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)

Marking Symbol:01

Packaging

Embossed type (Thermo-compression sealing) 3 000 pcs / reel (standard)

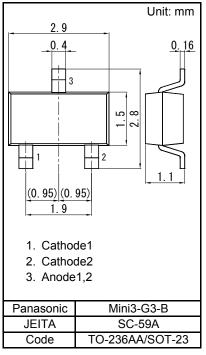
■ Absolute Maximum Ratings Ta = 25 °C

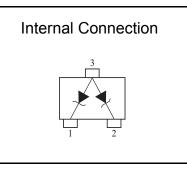
Parameter	Symbol	Rating	Unit
Total power dissipation <sup>*1</sup>	PT	200	mW
Electrostatic discharge <sup>*2</sup>	ESD	±10	kV
Junction temperature	Tj	150	°C
Operating ambient temperature	Topr	-40 to +85	°C
Storage temperature	Tsta	-55 to +150	°C

Note) \*1: Mounted on glass epoxy print board. ( 45 mm x 45 mm x 1 mm) (2 Diode total)

Solder in (1.0 mm x 1.0 mm)

\*2: Test method:IEC61000\_4\_2(C = 150 pF,R = 330 Ω, Contact discharge:10 times)





#### ■ Electrical Characteristics Ta = 25 °C ± 3 °C

Deremeter	Symbol	Conditions	Min	Tun	Max	Linit
Parameter	Symbol	Conditions	IVIIII	Тур	Max	Unit
Forward voltage	VF	IF = 10 mA			1.0	V
Zener voltage *1, *2	VZ	IZ = 5 mA	5.89		6.51	V
Zener operating resistance	RZ	IZ = 5 mA			50	Ω
Zener rise operating resistance	RZK	IZ = 0.5 mA			100	Ω
Reverse current	IR	VR = 4 V			0.2	μA
Temperature coefficient of zener voltage *3	SZ	IZ = 5 mA		2.3		mV/°C

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.

2. \*1: The temperature must be controlled 25°C for VZ mesurement.

VZ value measured at other temperature must be adjusted to VZ (25°C)

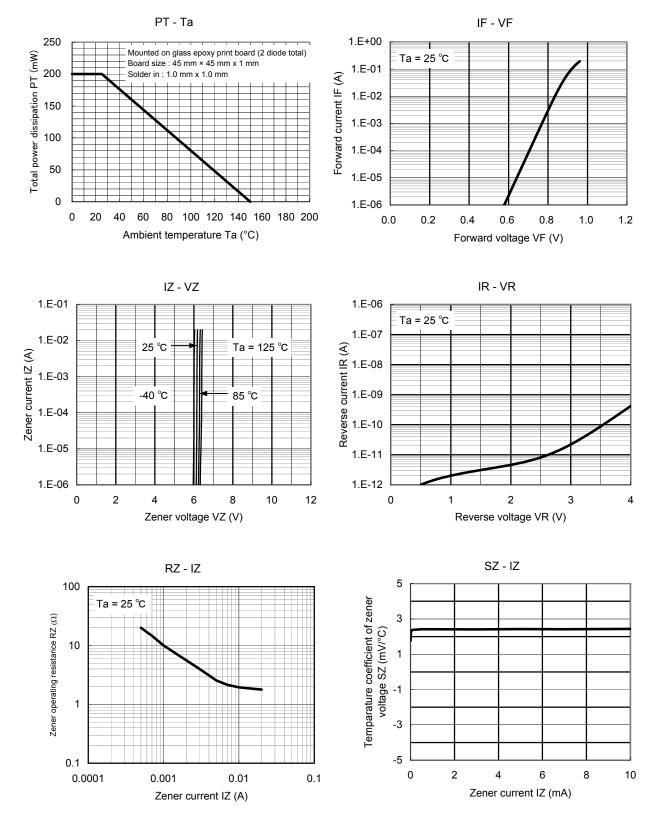
\*2: VZ guaranted 20 ms after current flow.

\*3: Tj = 25°C to 150°C



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### Technical Data (reference)



Established : 2010-05-17 Revised : 2013-10-22

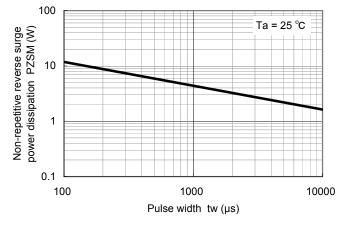
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#### Technical Data ( reference ) Rth - t Ct - VR 40 1000 35 Ta = 25 °C Terminal capacitance Ct (pF) (1) Thermal resistance Rth (°C/W) f = 1 MHz Rth(j-l) = 100 °C/W 30 (2) 100 25 20 15 10 (1) Non-heat sink 10 (2) Mounted on glass epoxy print board. 5 Board size : 45 mm × 45 mm x 1 mm Solder in : 1.0 mm x 1.0 mm 0 1 0 1 2 3 4 5 0.001 0.01 0.1 1 10 100 1000 Reverse voltage VR (V) Time t (s)

PZSM - tw

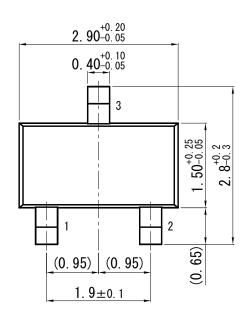


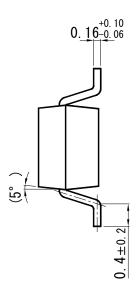


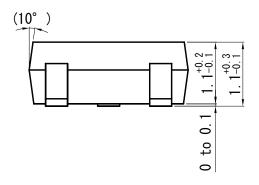
Mini3-G3-B

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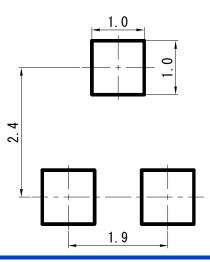
Unit: mm







Land Pattern (Reference) (Unit: mm)



Page 4 of 4

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